CMOS Digital Integrated Circuits Silicon Monolithic

TC7PCI3212MT,TC7PCI3215MT

1. Functional Description

2 Differential Channel, 2:1 multiplexer/demultiplexer switch for PCI Express Gen3

2. General

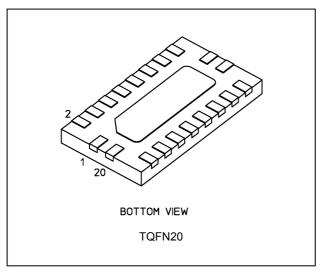
The TC7PCI3212MT and TC7PCI3215MT are 2 differential channel, 1-2 multiplexer/demultiplexer for PCI Express Gen3 (8Gbps), or other high-speed interface applications.

The An+/An- inputs is connected to the Bn+/Bn- or Cn+/Cn- outputs determined by the combination both the select input (SEL) and output enable (\overline{OE}) . When the output enable (\overline{OE}) input is held high-level, the switches are open (high-impedance state) with regardless the state of select inputs and reducing consumption current. All inputs are equipped with protection circuits against static discharge.

3. Features

- (1) Operating voltage: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
- (2) Switch terminal ON-capacitance: $C_{I/O} = 1.5 \text{ pF}$ Switch On (typ.) $@V_{CC} = 3.3 \text{ V}$
- (3) ON resistance: $R_{ON} = 7.5 \Omega$ (typ.) @ $V_{CC} = 3.0 \text{ V}$, $V_{IS} = 0 \text{ V}$
- (4) -3dB Bandwidth: BW = 11.5 GHz (typ.) @ V_{CC} = 3.3 V
- (5) Insertion Loss: DDIL = -1 dB (typ.) @ V_{CC} = 3.3 V, f = 4 GHz
- (6) Off Isolation: DDOIRR = -20 dB (typ.) @ V_{CC} = 3.3 V, f = 4 GHz
- (7) Crosstalk: DDNEXT = -40 dB (typ.) @ V_{CC} = 3.3 V, f = 4 GHz
- (8) ESD performance: Machine model $\geq \pm 200$ V, Human body model $\geq \pm 2000$ V
- (9) Package: TQFN20

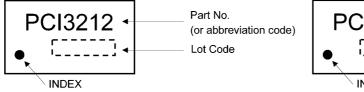
4. Packaging



5. Marking

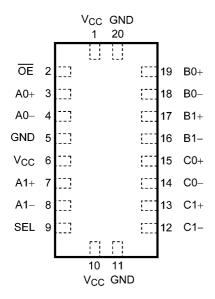
TC7PCI3212MT

TC7PCI3215MT

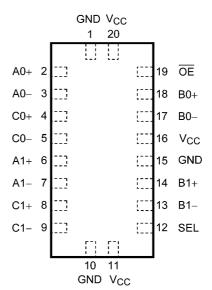


6. Pin Assignment

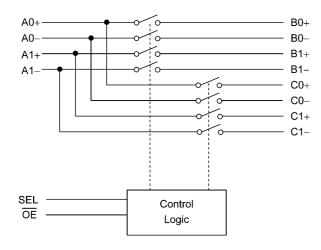
TC7PCI3212MT



TC7PCI3215MT



7. Block Diagram



8. Principle of Operation

8.1. Truth Table

Inputs OE	Inputs SEL	Function	Function
L	L	An+ port = Bn+ port, An- port = Bn- port	(n=0,1)
L	Н	An+ port = Cn+ port, An- port = Cn- port	(n=0,1)
Н	_	An, Bn, Cn port Disconnect	(n=0,1)

—: Don't care.



9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V_{CC}		-0.5 to 4.6	V
Input voltage (OE, SEL)	V _{IN}		-0.5 to 4.6	V
Switch I/O voltage	V _S		-0.5 to V _{CC} +0.5	V
Switch I/O current	I _S		50	mA
Power dissipation	P_{D}		500	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±50	mA
Storage temperature	T _{stg}		-55 to 125	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		3.0 to 3.6	V
Input voltage (OE, SEL)	V _{IN}		0 to 3.6	V
Switch I/O voltage	V _S		0 to V _{CC}	V
Operating temperature	T _{opr}		-40 to 85	°C
Input rise time	dt/dv		0 to 10	ns/V
Input fall time	dt/dv		0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either V_{CC} or GND.

11. Electrical Characteristics

11.1. DC Characteristics (Note) (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage (OE, SEL)	V _{IH}		_	3.0 to 3.6	0.65 × V _{CC}	_	_	٧
Low-level input voltage (OE, SEL)	V _{IL}		_	3.0 to 3.6		_	0.35 × V _{CC}	V
Input leakage current (OE, SEL)	I _{IN}		V _{IN} = 0 to 3.6 V	3.0 to 3.6		_	±1	μА
Switch OFF-state leakage current	I _{SZ}		$\frac{V_{IS}}{OE} = 0 \text{ to } V_{CC},$ $\frac{V_{IS}}{OE} = V_{CC}$	3.0 to 3.6	_	_	±1	μА
ON-resistance	R _{ON}	(Note 1)	V _{IS} = 0 V, I _{IS} = 30 mA	3.0	_	7.5	11.5	Ω
	R _{ON}	(Note 1)	V _{IS} = 1.2 V, I _{IS} = 30 mA	3.0	_	8.5	13.5	Ω
Difference of ON-resistance between switches (bit to bit)	ΔR _{ON}	(Note 1)	V _{IS} = 0 V, 1.2 V, I _{IS} = 15 mA	3.0		0.1	_	Ω
ON-resistance flatness	R _{ON(flat)}	(Note 1)	V _{IS} = 0 V to 1.2 V, I _{IS} = 15 mA	3.0	_	1	_	Ω
Quiescent supply current	I _{CC}		$\frac{V_{IN}}{OE} = V_{CC}$ or GND, $\frac{V_{CC}}{OE} = V_{CC}$	3.6	_	_	1	μА
Quiescent supply current	I _{CC}		$\frac{V_{IN}}{OE} = V_{CC} \text{ or GND},$ $\frac{V_{IN}}{OE} = \frac{V_{CC}}{V_{CC}} = \frac{V_{CC}}{$	3.6	_	200	500	μА

Note : All typical values are at $T_a = 25$ °C.

Note 1: ON-resistance is measured by measuring the voltage drop across the switch at the indicated current.



11.2. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} / t _{PHL}	(Note 1)	$C_L = 5 \text{ pF}$ See Fig. 12.1	3.3 ± 0.3	_	0.1	_	ns
Turn-ON time (SEL to Output)	t _{on}		R_L = 50 Ω , C_L = 5 pF See Fig. 12.2	3.3 ± 0.3		10	15	ns
Turn-ON time (OE to Output)	t _{on}		R_L = 50 Ω , C_L = 5 pF See Fig. 12.2	3.3 ± 0.3	_	37	50	μS
Turn-OFF time (SEL to Output)	t _{off}		R_L = 50 Ω , C_L = 5 pF See Fig. 12.2	3.3 ± 0.3		3.5	5	ns
Turn-OFF time (OE to Output)	t _{off}		R_L = 50 Ω , C_L = 5 pF See Fig. 12.2	3.3 ± 0.3		5	6.5	ns
Break before make	TBBM		R_L = 50 Ω , C_L = 5 pF See Fig. 12.3	3.3 ± 0.3	3		9	ns
Output skew (bit to bit)	t _{SK(b)}	(Note 1)	C_L = 5 pF See Fig. 12.4	3.3 ± 0.3		5	_	ps
Output skew (channel to channel)	t _{SK(CH)}	(Note 1)	C_L = 5 pF See Fig. 12.5	3.3 ± 0.3		10	_	ps
Differential OFF isolation	DDOIRR	(Note 1)	R_T = 50 Ω , f = 4 GHz See Fig. 12.6	3.3 ± 0.3	_	-20	_	dB
Differential Near-end crosstalk	DDNEXT	(Note 1)	R_T = 50 Ω , f = 4 GHz See Fig. 12.7	3.3 ± 0.3	_	-40	_	dB
Differential return loss	DDRL	(Note 1)	R_T = 50 Ω , f = 4 GHz See Fig. 12.8	3.3 ± 0.3		-20	_	dB
Differential insertion loss	DDIL	(Note 1)	R_T = 50 Ω , f = 4 GHz See Fig. 12.8	3.3 ± 0.3		-1	_	dB
-3dB Bandwidth	BW	(Note 1)	R_T = 50 Ω , C_L = 0 pF See Fig. 12.8	3.3 ± 0.3		11.5	_	GHz

Note : All typical values are at $T_a = 25$ °C.

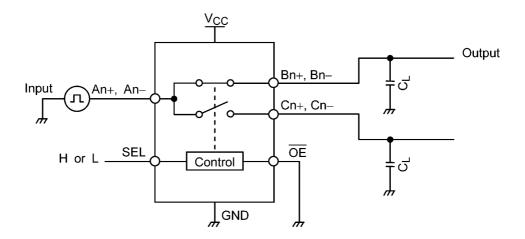
Note 1: This parameter is guaranteed by design.

11.3. Capacitive Characteristics (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance (OE, SEL)	C _{IN}		V _{IN} = 0 V	3.3	3	pF
Switch terminal OFF-capacitance (An+, An-)	C _{I/O}		$\overline{OE} = V_{CC}, V_{IS} = 0 V$	3.3	8.0	pF
Switch terminal OFF-capacitance (Bn+, Bn-, Cn+, Cn-)			$\overline{OE} = V_{CC}, V_{IS} = 0 V$	3.3	0.5	pF
Switch terminal ON-capacitance	C _{I/O}		OE = GND, V _{IS} = 0 V	3.3	1.5	pF

Note: Parameter guaranteed by design.

12. AC Electrical Test Circuit (Fig)



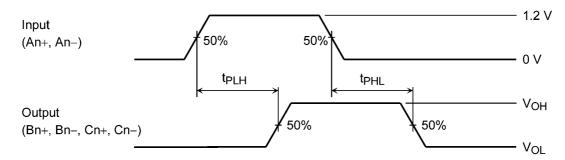
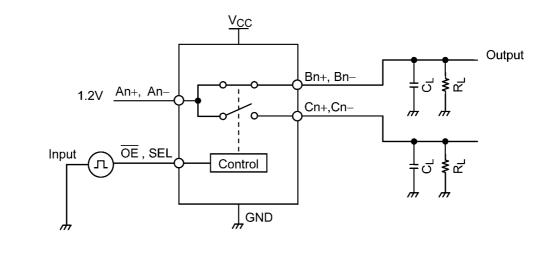


Fig. 12.1 Propagation delay time



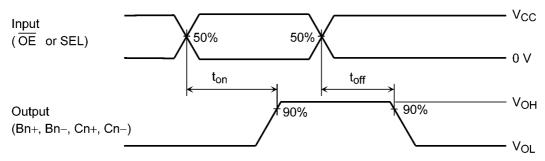


Fig. 12.2 Turn-ON and Turn-OFF time

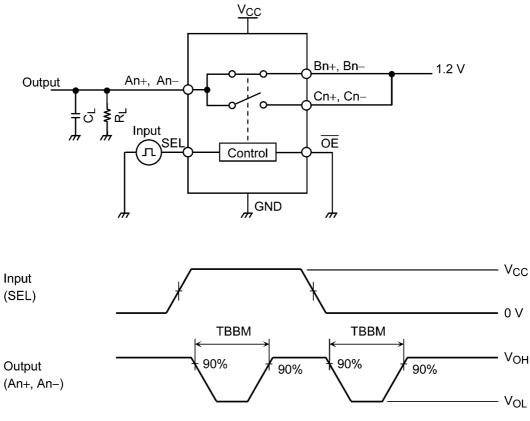
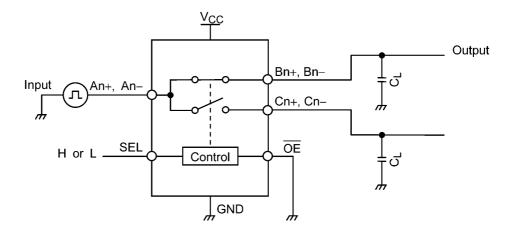


Fig. 12.3 Break before make



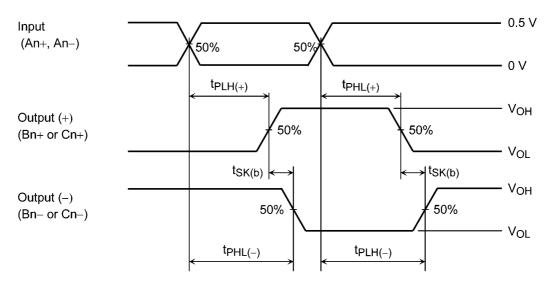


Fig. 12.4 Output skew (bit to bit)

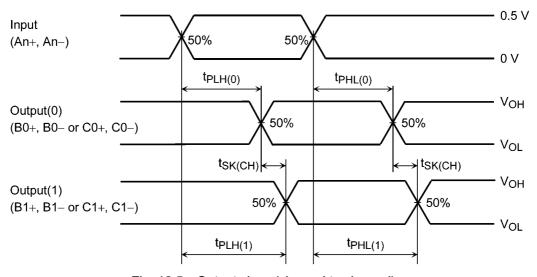


Fig. 12.5 Output skew (channel to channel)

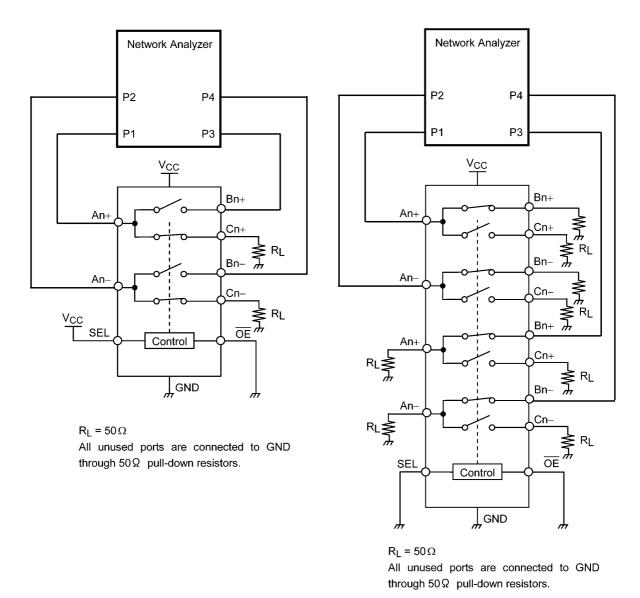
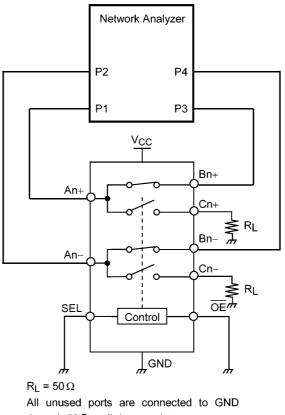


Fig. 12.6 Differential OFF isolation

Fig. 12.7 Differential Near-end crosstalk



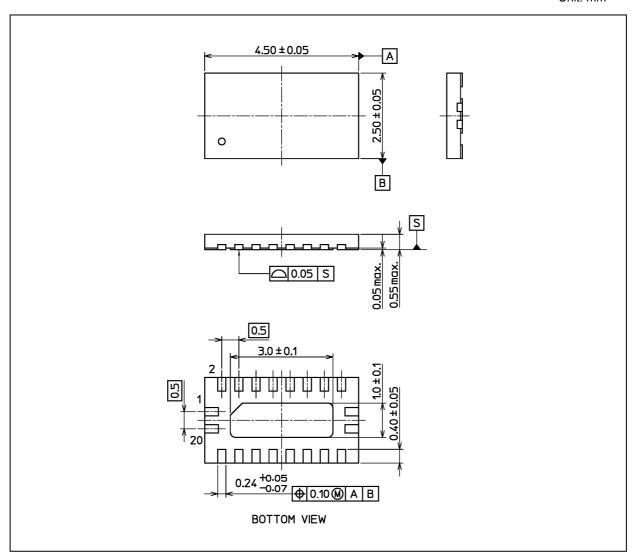
through $50\,\Omega$ pull-down resistors.

Fig. 12.8 Differential return loss, Differential insertion loss, -3dB Bandwidth



Package Dimensions

Unit: mm



Weight: 0.017 g (typ.)

Package Name(s)
TOSHIBA: P-UQFN20-0305-0.50-001
Nickname: TQFN20



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